

MOSFET Power Loss Calculations for Given MOSFET

```
[requiredTJA, LossM1, LossM3, LossM4]=CalculateBoostModeSwitchPowerDissipation(6, 4.5, 5.5, 70,
```

Displaying Values

```
disp('INDUCTOR & INDUCTOR CURRENT & DUTY CYCLE');
```

INDUCTOR & INDUCTOR CURRENT & DUTY CYCLE

```
disp(['Maximum Duty Cycle of third Mosfet: %',num2str(D3maxBoost*100)]);
```

Maximum Duty Cycle of third Mosfet: %35.7143

```
disp(['Inductor Current Value in Boost Region: ',num2str(IInductorBoost),'A']);
```

Inductor Current Value in Boost Region: 55.5556A

```
disp(['Inductor Current Value in Buck Region: ',num2str(IInductorBuck),'A']);
```

Inductor Current Value in Buck Region: 35.7143A

```
disp(['Inductor Ripple Current Value in Boost Region: ', num2str(IInductorRippleBoost),'A']);
```

Inductor Ripple Current Value in Boost Region: 16.6667A

```
disp(['Inductor Ripple Current Value in Buck Region: ',num2str(IInductorRippleBuck),'A']);
```

Inductor Ripple Current Value in Buck Region: 1.8874A

```
disp(['Inductor Current Peak in Buck Region: ',num2str(IInductorPeakBuck),'A']);
```

Inductor Current Peak in Buck Region: 36.658A

```
disp(['Inductor Current Peak in Boost Region: ', num2str(IInductorPeakBoost),'A']);
```

Inductor Current Peak in Boost Region: 63.8889A

```
disp(['Minimum Inductor Current Satisfying the Ripple Current Condition: ',num2str(L*10^6),' micro Henry']);
```

Minimum Inductor Current Satisfying the Ripple Current Condition: 3.8571 micro Henry

```
disp(' ');
```

```
disp('SATISFACTION OF INDUCTANCE CONDITIONS & SENSE RESISTOR');
```

SATISFACTION OF INDUCTANCE CONDITIONS & SENSE RESISTOR

```
if L>Lmin1Buck && L>Lmin1Boost && L>Lmin2Boost
    disp('Chosen Inductance Value Satisfies the Minimum Inductance Conditions')
else
    disp('Chosen Inductance Value Does Not Satisfy the Minimum Inductance Conditions')
end
```

Chosen Inductance Value Satisfies the Minimum Inductance Conditions


```

M3Duty=1-Vin/Vout;
M4Duty=1-M3Duty;
ILoad=Power/Vout;
IIn=ILoad/M4Duty;

%M1 loss
IM1rms=M1Duty*IIn;
conductionLossM1=RDSOn*IM1rms^2;

%M3 loss
IM3rms=M3Duty*ILoad;
conductionLossM3=RDSOn*IM3rms^2;
switchingLossM3=0.5*Vout*(tr+tf)*freq*IM3rms;

%M4 loss
IM4rms=M4Duty*ILoad;
conductionLossM4=RDSOn*IM4rms^2;
switchingLossM4=0.5*Vout*(tr+tf)*freq*IM4rms;

M1Power=conductionLossM1;
M3Power=conductionLossM3+switchingLossM3;
M4Power=conductionLossM4+switchingLossM4;
TJA=[(Tmax-Tamb)/M1Power,(Tmax-Tamb)/M3Power,(Tmax-Tamb)/M4Power];
requiredTJA=min(TJA);
end

```

Appendix-3: Switch Power Dissip Calculator for Given MOSFET Ratings

```

% will not be used this script as there will be used single MOSFET per gate
% power will be handled by heatsinks and layout

% function [numberOfM1, M1Power, numberOfM3, M3Power, numberOfM4, M4Power]=CalculateBoostModeN
% RDSOn=RDSOnInMiliOhm*0.001;
% tr=trInNanoSec*10^-9;
% tf=tfInNanoSec*10^-9;
% M1Duty=1;
% M3Duty=1-Vin/Vout;
% M4Duty=1-M3Duty;
% conductionLossM1=10;
% conductionLossM3=10;
% conductionLossM4=10;
% switchingLossM3=10;
% switchingLossM4=10;
% ILoad=Power/Vout;
% IIn=ILoad/M4Duty;
%
% %M1 loss
% n=1;
% while Tamb+conductionLossM1*RthermalJA>Tmax
% IM1rms=M1Duty*IIn/n;

```

```

%      conductionLossM1=RDSOn*IM1rms^2;
%      if(n>3)
%          disp('Too many MOSFETs in parallel are needed!!');
%          disp('Do not use this MOSFET as SW1!!!!');
%          break;
%      end
%      n=n+1;
%  end
%  numberOfM1=n;
%  M1Power=conductionLossM1;
%
%  %M3 loss
%  n=1;
%  while Tamb+(conductionLossM3+switchingLossM3)*RthermalJA>Tmax
%      IM3rms=(M3Duty*ILoad/n);
%      conductionLossM3=RDSOn*IM3rms^2;
%      switchingLossM3=0.5*Vout*(tr+tf)*freq*IM3rms;
%      if(n>3)
%          disp('Too many MOSFETs in parallel are needed!!');
%          disp('Do not use this MOSFET as SW3!!!!');
%          break;
%      end
%      n=n+1;
%  end
%  numberOfM3=n;
%  M3Power=conductionLossM3+switchingLossM3;
%
%  %M4 loss
%  n=1;
%  while Tamb+(conductionLossM4+switchingLossM4)*RthermalJA>Tmax
%      IM4rms=(M4Duty*ILoad/n);
%      conductionLossM4=Vsd*IM4rms;
%      switchingLossM4=0.5*Vout*(tr+tf)*freq*IM4rms;
%      if(n>3)
%          disp('Too many MOSFETs in parallel are needed!!');
%          disp('Do not use this MOSFET as SW4!!!!');
%          break;
%      end
%      n=n+1;
%  end
%  numberOfM4=n;
%  M4Power=conductionLossM4+switchingLossM4;
% end

```

Appendix-4: Output Ripple Calculator for Given Capacitor Ratings

```

function [requiredNumOfCaps, ripple,requiredNumOfCapsUpdated, rippleUpdated]=CalculateOutputRi
if~exist('numberOfAdditionalCaps','var')
    numberOfAdditionalCaps=0;
end

```

```

VinMin=18;
Vout=28;
n=1;
Iout=Power/Vout;
var1=1;
    while var1>0.01*Vout
        n=n+1;
        %%Output Ripple Formula provided in the datasheet
        var1=Iout*(Vout-VinMin)/freq/(n*capacitanceInuF*10^-6)/VinMin+Power*(ESRInmOhm*10^-3/n);
        if(n>10)
            disp('Too many capacitor is needed to satisfy ripple conditions. ');
            disp(' Do not use this capacitor for your application! ');
            break;
        end
    end
    if(mod(n,2))
        requiredNumOfCaps=n+1;
        ripple=Iout*(Vout-VinMin)/freq/((n+1)*capacitanceInuF*10^-6)/VinMin+Power*(ESRInmOhm*10^-3/(n+1));
        disp(['Required number of specified capacitor is odd.', 'For layout it is increased by 1.']);
    else
        ripple=var1;
        requiredNumOfCaps=n;
    end
    if(numberOfAdditionalCaps)
        requiredNumOfCapsUpdated=numberOfAdditionalCaps+requiredNumOfCaps;
        rippleUpdated=Iout*(Vout-VinMin)/freq/(requiredNumOfCapsUpdated*capacitanceInuF*10^-6)/VinMin+Power*(ESRInmOhm*10^-3/requiredNumOfCapsUpdated);
    else
        requiredNumOfCapsUpdated=requiredNumOfCaps;
        rippleUpdated=ripple;
    end
end

```